

DUAL-OUTPUT LOW-DROPOUT LINEAR REGULATOR

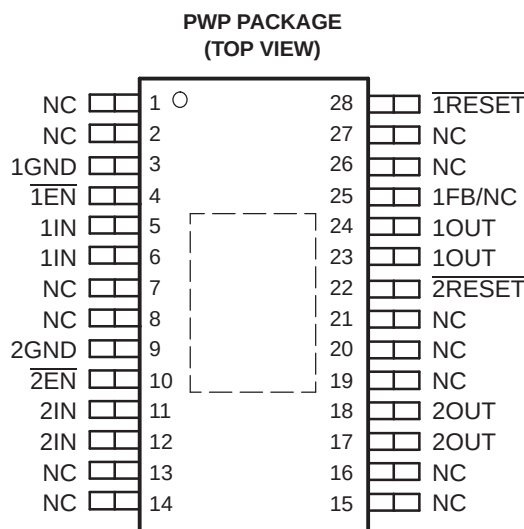
Check for Samples: [TPS767D301-EP](#)

FEATURES

- Controlled Baseline
 - One Assembly/Test Site, One Fabrication Site
- Extended Temperature Performance of -55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree
- 1- μA Quiescent Current During Shutdown
- Dual Open-Drain Power-On Reset With 200-ms Delay for Each Regulator
- 28-Pin PowerPAD™ TSSOP Package
- Thermal Shutdown Protection for Each Regulator

Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- Dual Output Voltages for Split-Supply Applications
- Output Current Range of 0 mA to 1.0 A Per Regulator
- 3.3-V/Adjustable Output
- Fast Transient Response
- 3% Tolerance Over Load and Temperature
- Dropout Voltage Typically 350 mV at 1 A
- Ultra-Low 85- μA Typical Quiescent Current



NC – No internal connection

DESCRIPTION/ORDERING INFORMATION

The TPS767D301-EP dual-voltage regulator offers fast transient response, low dropout (LDO) voltages, and dual outputs in a compact package and incorporates stability with 10- μF low-ESR output capacitors.

The TPS767D301-EP dual-voltage regulator is designed primarily for DSP applications. This device can be used in any mixed-output voltage application, with each regulator supporting up to 1 A. Dual active-low reset (RESET) signals allow resetting of core logic and I/O separately.

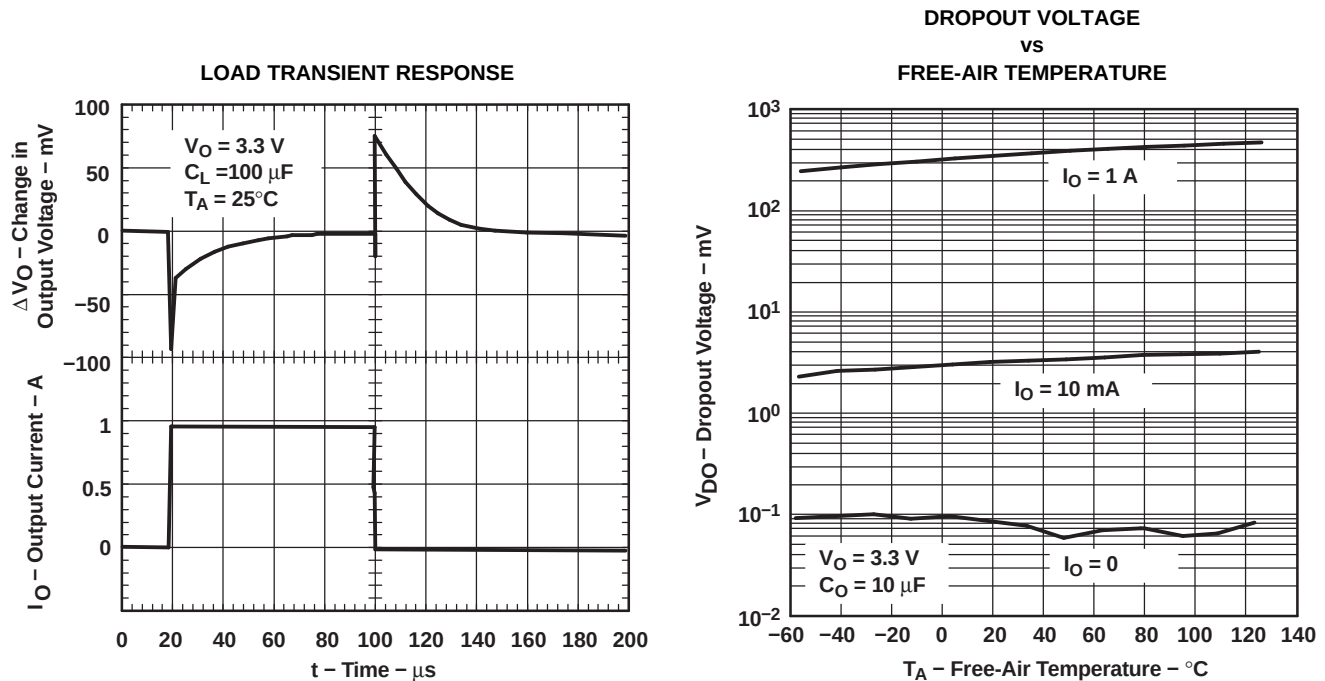
Table 1. ORDERING INFORMATION

T_J	REGULATOR 1 V_O	REGULATOR 2 V_O	TSSOP (PWP)
-55°C to 125°C	Adjustable (1.5 V to 5.5 V)	3.3 V	TPS767D301MPWPREP



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

DESCRIPTION/ORDERING INFORMATION (CONTINUED)



Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low and is directly proportional to the output current. Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is very low and independent of output loading (typically 85 μ A over the full range of output current, 0 mA to 1 A). These two key specifications yield a significant improvement in operating life for battery-powered systems. This LDO device also features a sleep mode; applying a TTL high signal to enable ($\overline{\text{EN}}$) shuts down the regulator, reducing the quiescent current to 1 μ A at $T_J = 25^\circ$ C.

The $\overline{\text{RESET}}$ output of the TPS767D301-EP initiates a reset in microcomputer and microprocessor systems in the event of an undervoltage condition. An internal comparator in the TPS767D301-EP monitors the output voltage of the regulator to detect an undervoltage condition on the regulated output voltage.

The TPS767D301-EP is offered in an adjustable version (programmable over the range of 1.5 V to 5.5 V). Output voltage tolerance is specified as a maximum of 3% over line, load, and temperature ranges. The TPS767D301-EP is available in a 28-pin PWP (TSSOP) package. The device operates over a junction temperature range of -55° C to 125° C.

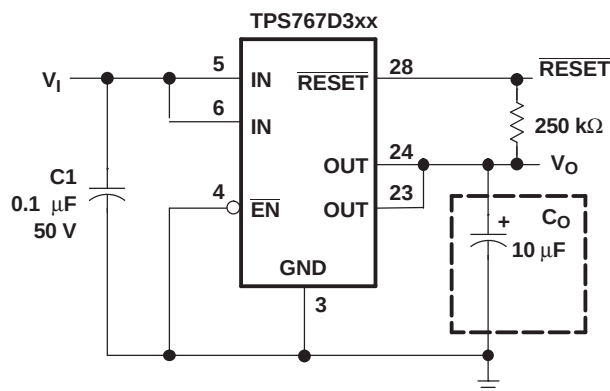
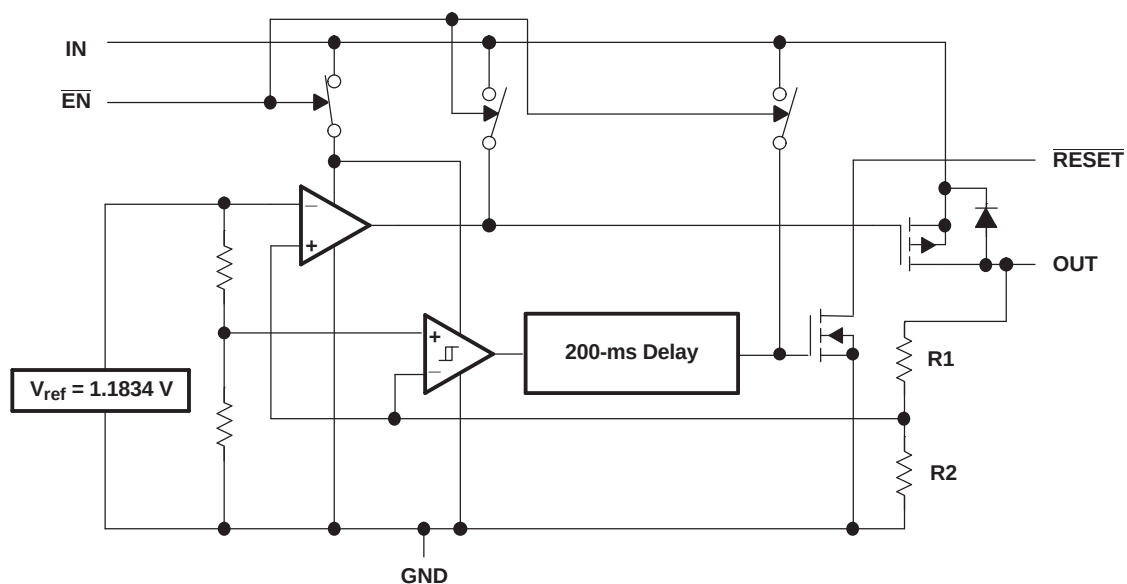
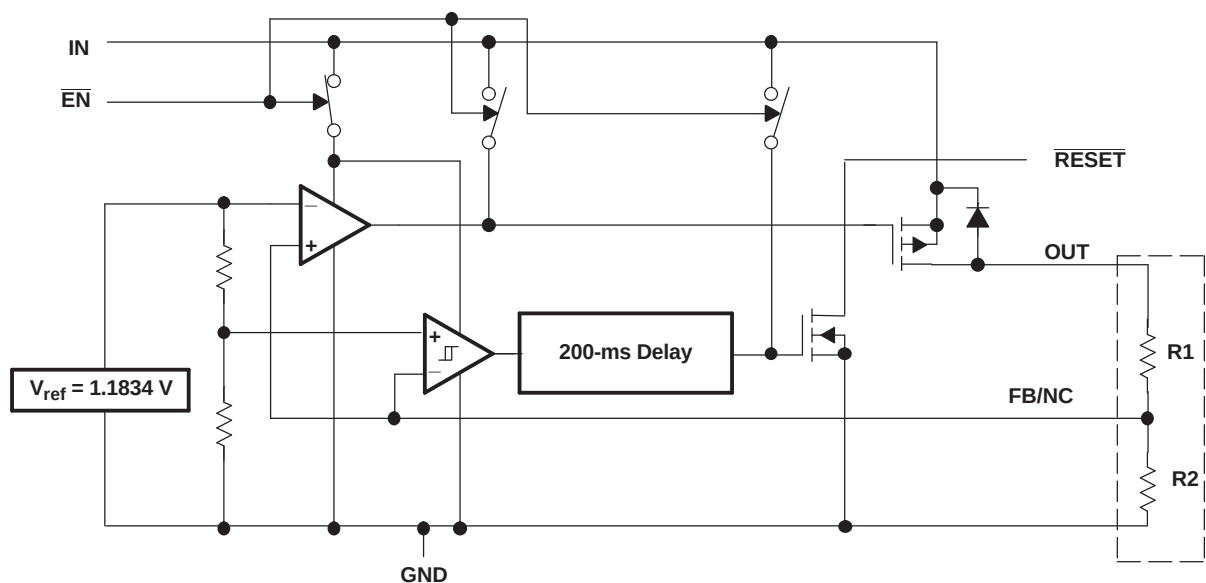


Figure 1. Typical Application Circuit (Fixed Versions) for Single Channel

FUNCTIONAL BLOCK DIAGRAM Adjustable Version (for Each LDO)



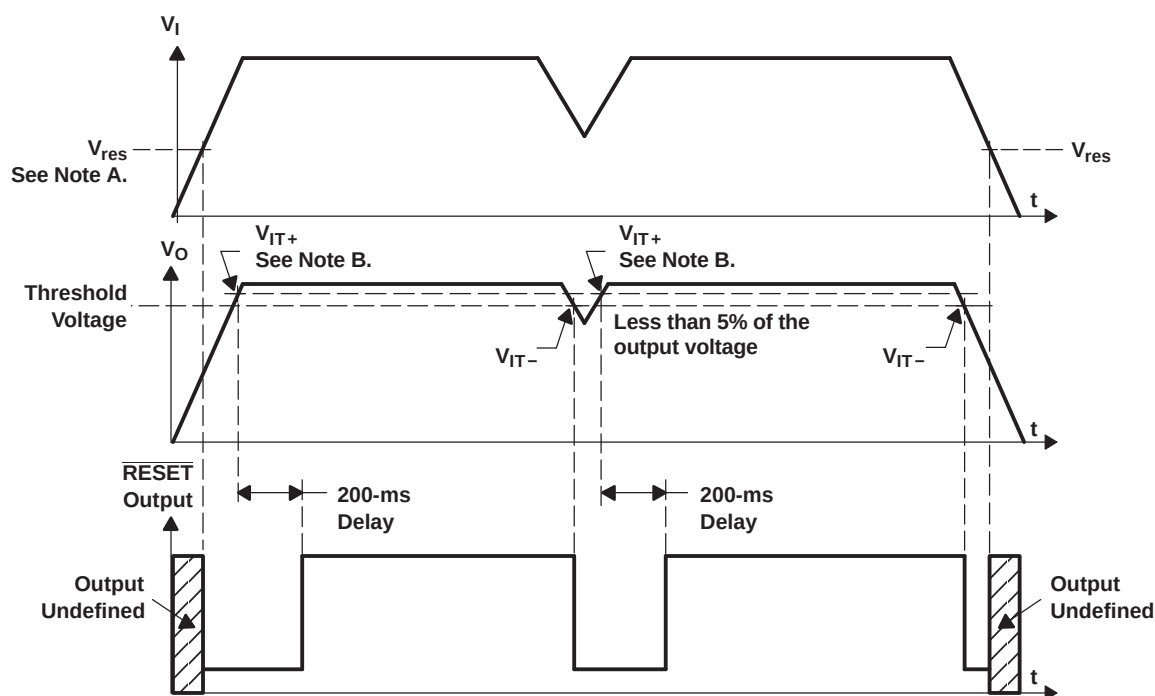
FUNCTIONAL BLOCK DIAGRAM Fixed-Voltage Version (for Each LDO)



External to the device

TERMINAL FUNCTIONS

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
1GND	3		Regulator 1 ground
$\overline{1EN}$	4	I	Regulator 1 enable
1IN	5, 6	I	Regulator 1 input supply voltage
2GND	9		Regulator 2 ground
$\overline{2EN}$	10	I	Regulator 2 enable
2IN	11, 12	I	Regulator 2 input supply voltage
2OUT	17, 18	O	Regulator 2 output voltage
$\overline{2RESET}$	22	O	Regulator 2 reset
1OUT	23, 24	O	Regulator 1 output voltage
1FB/NC	25	I	Regulator 1 output voltage feedback for adjustable version and no connect for fixed-output version
$\overline{1RESET}$	28	O	Regulator 1 reset
NC	1, 2, 7, 8, 13–16, 19–21, 26, 27		No connection

TIMING DIAGRAM

- A. V_{res} is the minimum input voltage for a valid $\overline{RESET}$. The symbol V_{res} is not currently listed within EIA or JEDEC standards for semiconductor symbology.
- B. V_{IT} – Trip voltage typically is 5% lower than the output voltage (95% V_o).

Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

			MIN	MAX	UNIT
V _I	Input voltage range ⁽²⁾		−0.3	13.5	V
V _I	Input voltage range	1IN, 2IN, $\overline{\text{EN}}$	−0.3	V _I + 0.3	V
V _O	Output voltage	1OUT, 2OUT		7	V
		$\overline{\text{RESET}}$		16.5	
	Peak output current		Internally limited		
HBM	ESD rating			2	kV
	Continuous total power dissipation		See Dissipation Rating Table		
T _J	Operating virtual junction temperature range		−55	150	°C
T _{stg}	Storage temperature range		−65	150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal.

Table 2. DISSIPATION RATING TABLE

PACKAGE	AIR FLOW (CFM)	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
PWP ⁽¹⁾	0	3.58 W	35.8 mW/°C	1.97 W	1.43 W
	250	5.07 W	50.7 mW/°C	2.79 W	2.03 W

- (1) This parameter is measured with the recommended copper heat-sink pattern on a four-layer PCB, 1-oz copper on 4-in × 4-in ground layer. For more information, refer to TI technical brief literature number SLMA002.

Recommended Operating Conditions

			MIN	MAX	UNIT
V _I	Input voltage ⁽¹⁾	1IN, 2IN	2.7	10	V
I _O	Output current for each LDO ⁽²⁾		0	1	A
V _O	Output voltage range	1OUT, 2OUT	1.5	5.5	V
T _J	Operating virtual junction temperature		−55	125	°C

- (1) To calculate the minimum input voltage for maximum output current, use the following equation:
- $$V_{I(\min)} = V_{O(\max)} + V_{DO(\max \text{ load})}$$
- (2) Continuous output current and operating junction temperature are limited by internal protection circuitry, but it is not recommended that the device operate under conditions beyond those specified in this table for extended periods of time.

Electrical Characteristics

$V_I = V_{O(nom)} + 1\text{ V}$, $I_O = 1\text{ mA}$, $\overline{\text{EN}} = 0$, $C_O = 10\text{ }\mu\text{F}$ (unless otherwise noted)

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
V _O	Output voltage ⁽¹⁾	Adjustable	1.5 V ≤ V _O ≤ 5.5 V, 10 μA < I _O < 1 A	T _J = 25°C	V _O		V	
				T _J = −55°C to 125°C	0.97V _O	1.02V _O		
		3.3-V output	4.3 V < V _I < 10 V, 10 μA < I _O < 1 A	T _J = 25°C	3.3			
				T _J = −55°C to 125°C	3.201	3.366		
Quiescent current (GND current) for each LDO ⁽¹⁾			10 μA < I _O < 1 A, T _J = 25°C		85		μA	
			I _O = 1 A, T _J = −55°C to 125°C		125			
ΔV _O /V _O Output voltage line regulation for each LDO ^{(1) (2)}			V _O + 1 V < V _I ≤ 10 V, T _J = 25°C		0.01		%/V	
Output noise voltage			BW = 200 Hz to 100 kHz, V _O = 1.8 V, I _C = 1 A, C _O = 10 μF, T _J = 25°C		55		μV _{RMS}	
Output current limit for each LDO			V _O = 0 V		1.7		2	A
Thermal shutdown junction temperature					150			°C
Standby current for each LDO			2.7 V < V _I < 10 V, $\overline{\text{EN}}$ = V _I	T _J = 25°C	1		μA	
				T _J = −55°C to 125°C	10			
FB input current		Adjustable	FB = 1.5		2		nA	
High-level enable input voltage					2		V	
Low-level enable input voltage							0.8	V
Power-supply ripple rejection ⁽¹⁾			f = 1 KHz, T _J = 25°C, C _O = 10 μF		60		dB	
Reset	Minimum input voltage for valid RESET		I _{O(RESET)} = 300 μA		1.1		V	
	Trip threshold voltage		V _O decreasing		92	98	%V _O	
	Hysteresis voltage		Measured at V _O		0.5			
	Output low voltage		V _I = 2.7 V, I _{O(RESET)} = 1 mA		0.15	0.4	V	
	Leakage current		V _(RESET) = 7 V				1	μA
	RESET time-out delay				200		mV	
Input current		$\overline{\text{EN}}$	$\overline{\text{EN}}$ = 0 V		−1	0	1	μA
			$\overline{\text{EN}}$ = V _I		−1		1	
Load regulation					3		mV	
Dropout voltage ⁽³⁾			V _O = 3.3 V, I _O = 1 A	T _J = 25°C	350		mV	
				T _J = −55°C to 125°C	575			

(1) The minimum IN operating voltage is 2.7 V or $V_{O(\text{typ})} + 1\text{ V}$, whichever is greater. The maximum IN voltage is 10 V .

(2) If $V_O \leq 1.8\text{ V}$ then $V_{I(\text{min})} = 2.7\text{ V}$, $V_{I(\text{max})} = 10\text{ V}$:

$$\text{Line regulator (mV)} = (\%/V) \times \frac{V_O(V_{I(\text{max})} - 2.7\text{ V})}{100} \times 1000$$

If $V_O \geq 2.5\text{ V}$, then $V_{I(\text{min})} = V_O + 1\text{ V}$, and $V_{I(\text{max})} = 10\text{ V}$:

$$\text{Line regulator (mV)} = (\%/V) \times \frac{V_O[V_{I(\text{max})} - (V_O + 1\text{ V})]}{100} \times 1000$$

(3) IN voltage equals $V_{O(\text{typ})} - 100\text{ mV}$; adjustable output voltage set to 3.3 V nominal with external resistor divider. Dropout voltage of 1.8 V and 2.5 V is limited by input voltage-range limitations.

TYPICAL CHARACTERISTICS

Table 3. TABLE OF GRAPHS

		FIGURE
Output voltage	vs Output current	3, 4, 5
	vs Free-air temperature	6, 7, 8
Ground current	vs Free-air temperature	9, 10
Power-supply ripple rejection	vs Frequency	11
Output spectral noise density	vs Frequency	12
Output impedance	vs Frequency	13
Dropout voltage	vs Free-air temperature	14
Line transient response		15, 17
Load transient response		16, 18
Output voltage	vs Time	19
Dropout voltage	vs Input voltage	20
Equivalent series resistance (ESR)	vs Output current, $T_A = 25^\circ\text{C}$	22
	vs Output current, $T_J = 125^\circ\text{C}$	23
	vs Output Current, $T_A = 25^\circ\text{C}$	24
	vs Output current, $T_J = 125^\circ\text{C}$	25

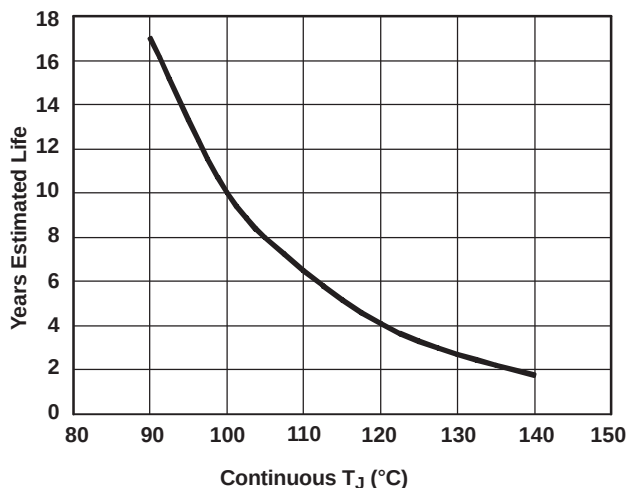


Figure 2. TPS767D301MPWPREP Estimated Device Life at Elevated Temperatures Wirebond Voiding Fail Mode

TYPICAL CHARACTERISTICS (continued)

**OUTPUT VOLTAGE
vs
OUTPUT CURRENT**

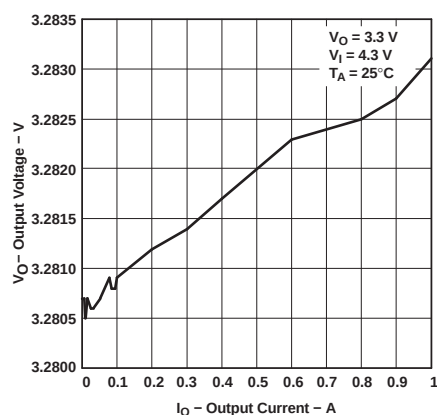


Figure 3.

**OUTPUT VOLTAGE
vs
OUTPUT CURRENT**

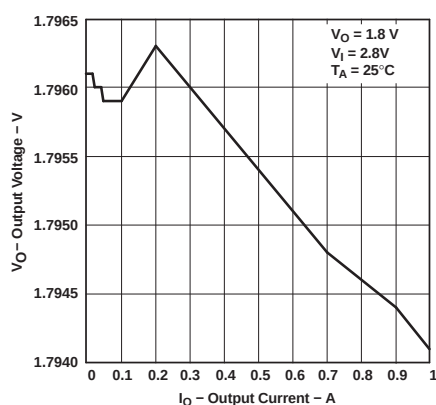


Figure 4.

**OUTPUT VOLTAGE
vs
OUTPUT CURRENT**

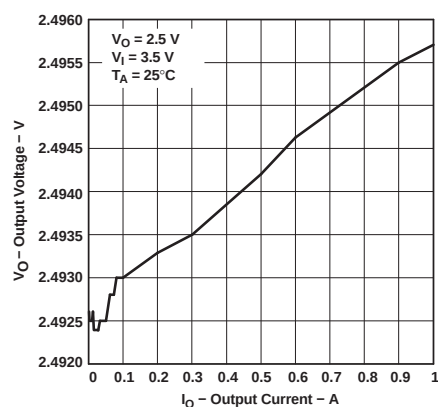


Figure 5.

**OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE**

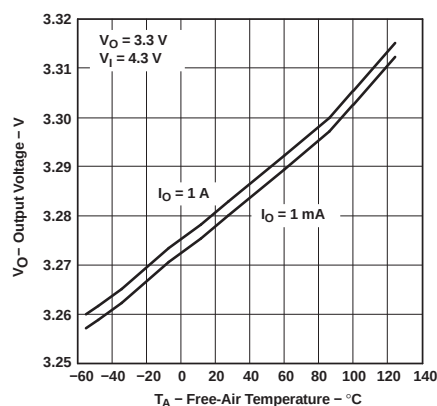


Figure 6.

**OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE**

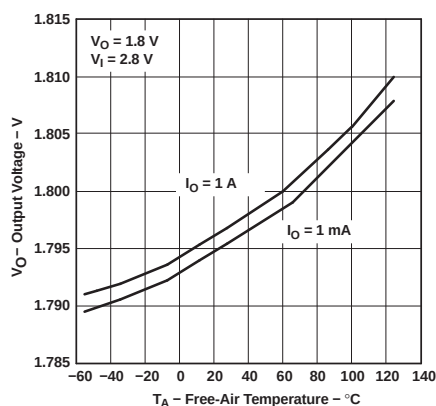


Figure 7.

**OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE**

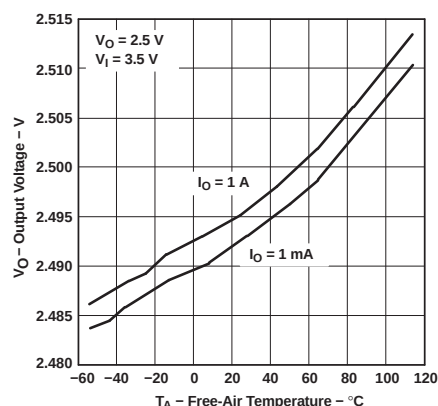


Figure 8.

TYPICAL CHARACTERISTICS (continued) (continued)

**GROUND CURRENT
VS
FREE-AIR TEMPERATURE**

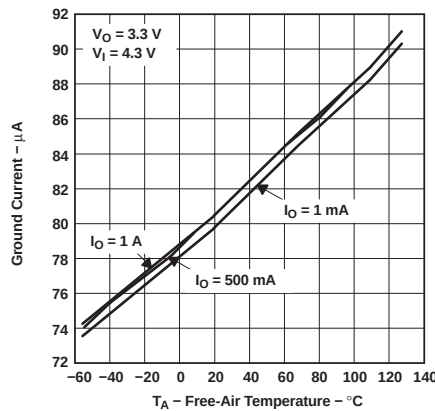


Figure 9.

**GROUND CURRENT
VS
FREE-AIR TEMPERATURE**

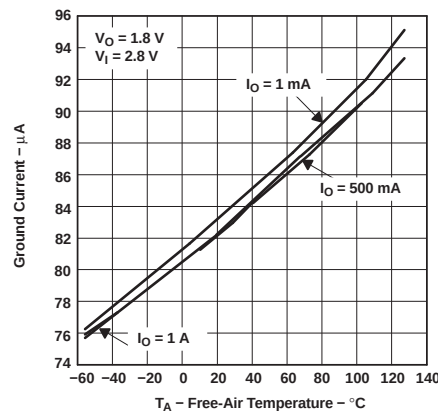


Figure 10.

**POWER-SUPPLY RIPPLE
REJECTION
VS
FREQUENCY**

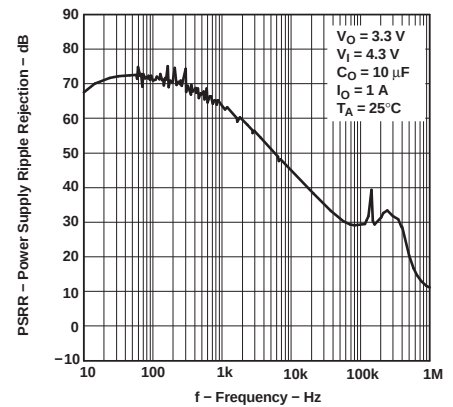


Figure 11.

**OUTPUT SPECTRAL NOISE
DENSITY
VS
FREQUENCY**

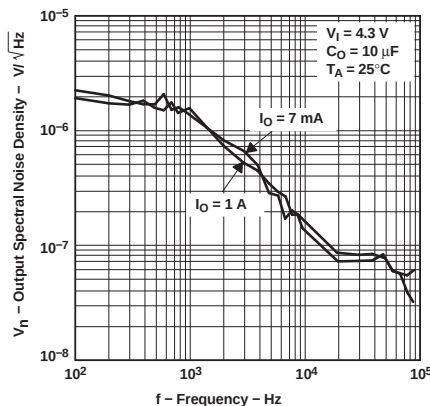


Figure 12.

**OUTPUT IMPEDANCE
VS
FREQUENCY**

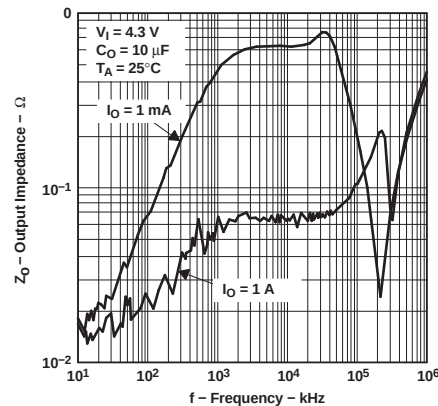


Figure 13.

**DROPOUT VOLTAGE
VS
FREE-AIR TEMPERATURE**

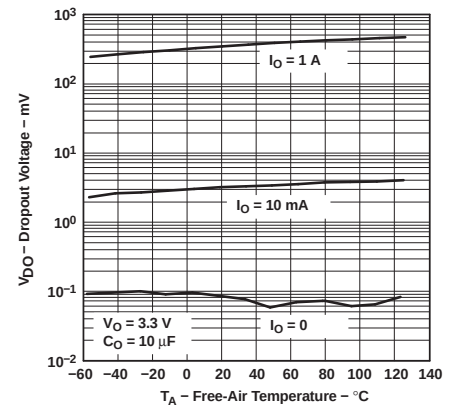


Figure 14.

LINE TRANSIENT RESPONSE

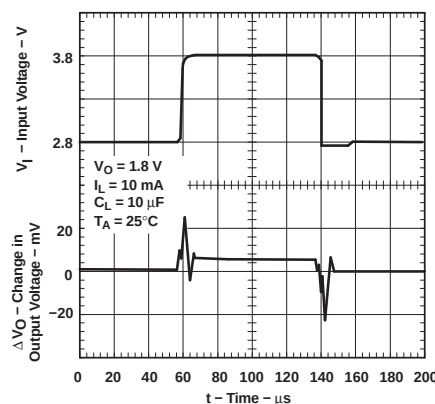


Figure 15.

LOAD TRANSIENT RESPONSE

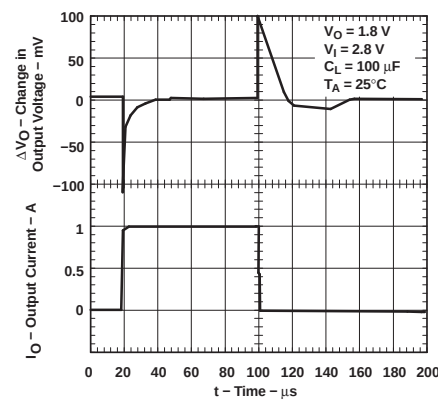


Figure 16.

LINE TRANSIENT RESPONSE

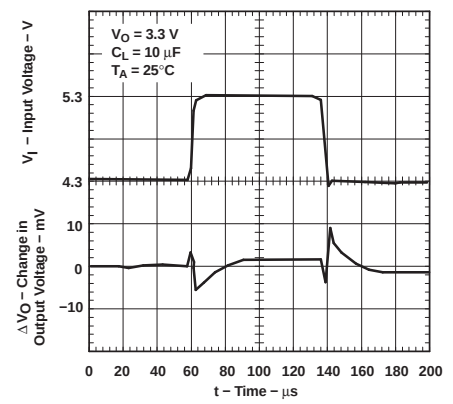


Figure 17.

TYPICAL CHARACTERISTICS (continued) (continued)

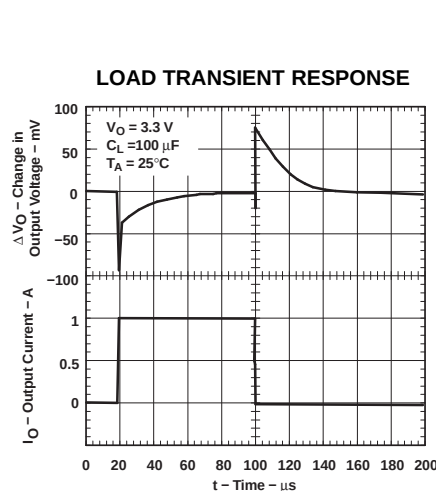


Figure 18.

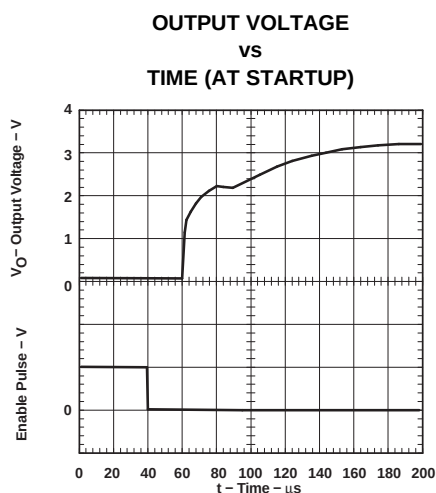


Figure 19.

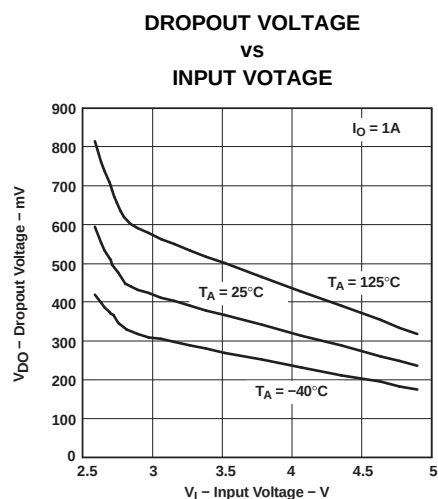


Figure 20.

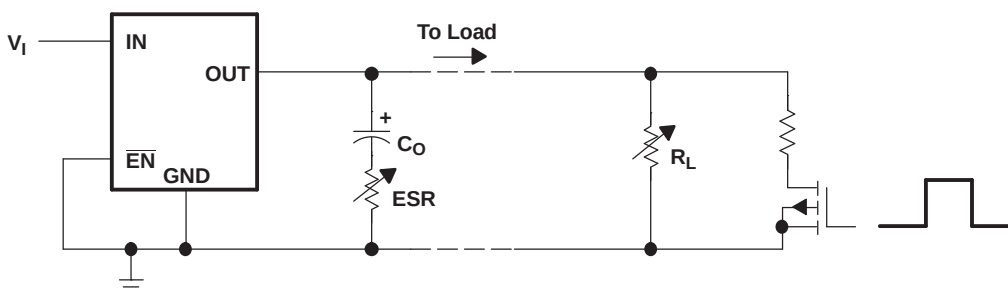


Figure 21. Test Circuit for Typical Regions of Stability
(Figure 22 Through Figure 25) (Fixed-Output Options)

TYPICAL CHARACTERISTICS (continued)⁽¹⁾

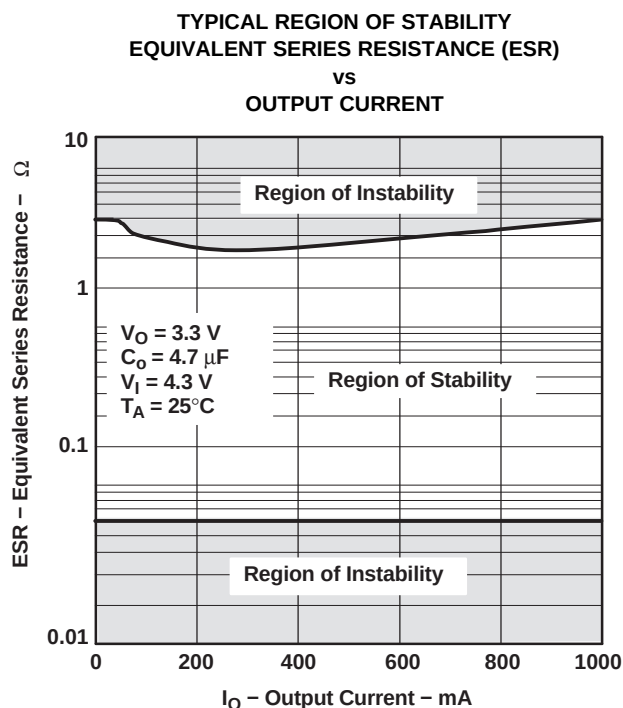


Figure 22.

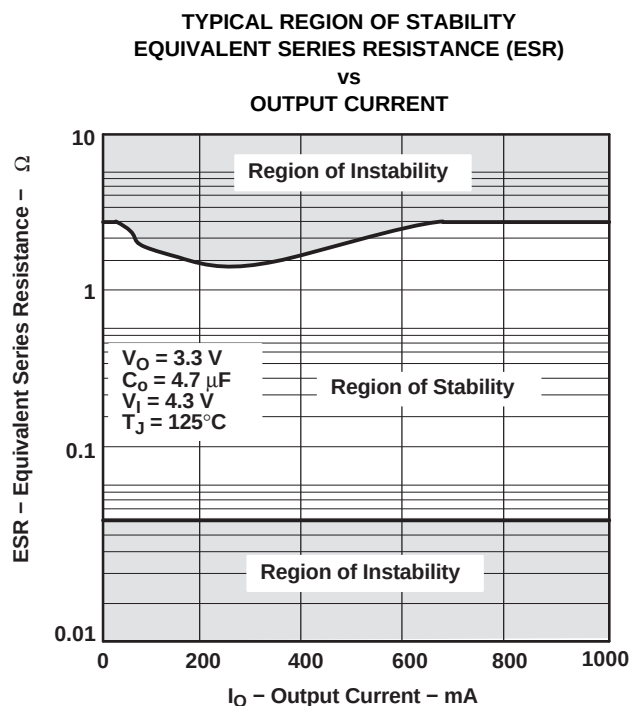


Figure 23.

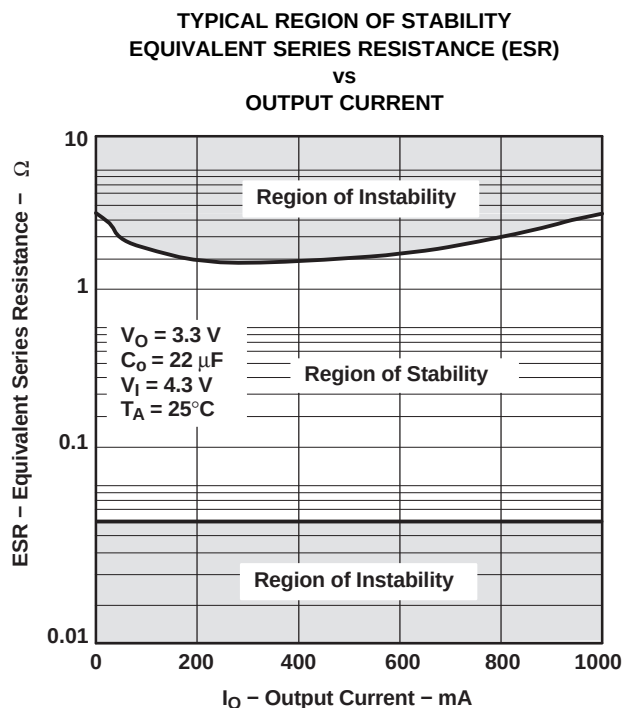


Figure 24.

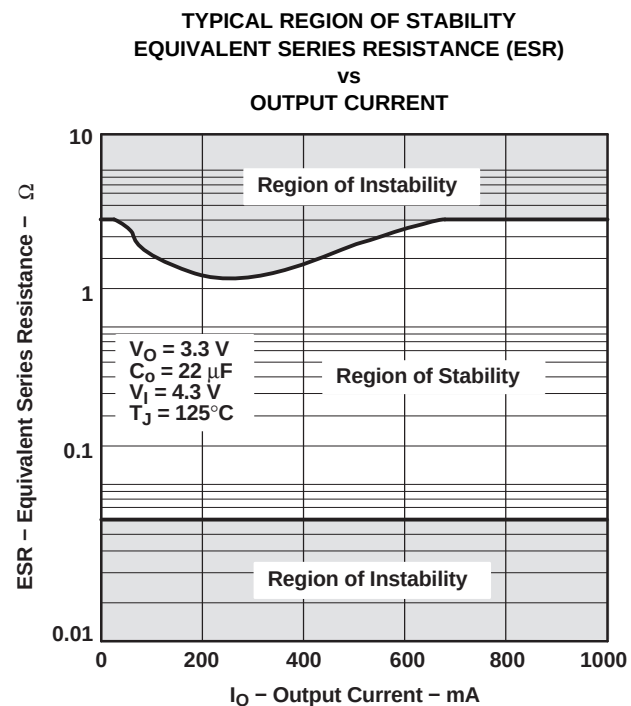


Figure 25.

(1) Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O .

APPLICATION INFORMATION

The features of the TPS767D301-EP (low-dropout voltage, ultra-low quiescent current, power-saving shutdown mode, and a supply-voltage supervisor) and the power-dissipation properties of the TSSOP PowerPAD package have enabled the integration of the dual LDO regulator with high output current for use in DSP and other multiple-voltage applications.

Device Operation

The TPS767D301-EP features very low quiescent current, which remains virtually constant even with varying loads. Conventional LDO regulators use a pnp pass element, the base current of which is directly proportional to the load current through the regulator ($I_B = I_C/\beta$). Close examination of the data sheets reveals that these devices typically are specified under near no-load conditions; actual operating currents are much higher, as evidenced by typical quiescent current versus load current curves. The TPS767D301-EP uses a PMOS transistor to pass current; because the gate of the PMOS is voltage driven, operating current is low and invariable over the full load range. The TPS767D301-EP specifications reflect actual performance under load conditions.

Another pitfall associated with the pnp-pass element is its tendency to saturate when the device goes into dropout. The resulting drop in β forces an increase in I_B to maintain the load. During power up, this translates to large start-up currents. Systems with limited supply current may fail to start up. In battery-powered systems, it means rapid battery discharge when the voltage decays below the minimum required for regulation.

The TPS767D301-EP quiescent current remains low, even when the regulator drops out, eliminating both problems. The TPS767D301-EP also features a shutdown mode that places the output in the high-impedance state (essentially equal to the feedback-divider resistance) and reduces quiescent current to under 2 μ A. If the shutdown feature is not used, $\overline{EN}$ should be tied to ground. Response to an enable transition is quick; regulated output voltage typically is reestablished in 120 μ s.

Minimum Load Requirements

The TPS767D301-EP is stable, even at zero load. No minimum load is required for operation.

FB – Pin Connection (Adjustable Version Only)

The FB pin is an input pin to sense the output voltage and close the loop for the adjustable option. The output voltage is sensed through a resistor divider network to close the loop (see [Figure 27](#)). Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit to improve performance at that point. Internally, FB connects to a high-impedance wide-bandwidth amplifier, and noise pickup feeds through to the regulator output. Routing the FB connection to minimize/avoid noise pickup is essential. In fixed-output options, this pin is a no connect.

External Capacitor Requirements

An input capacitor is not required; however, a ceramic bypass capacitor (0.047 pF to 0.1 mF) improves load transient response and noise rejection when the TPS767D301-EP is located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

Like all low dropout regulators, the TPS767D301-EP requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 10 μ F and the equivalent series resistance (ESR) must be between 60 m Ω and 1.5 Ω . Capacitor values of 10 μ F or larger are acceptable, provided the ESR is less than 1.5 Ω . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements previously described.

When it is necessary to achieve low height requirements along with high output current and/or high ceramic load capacitance, several higher ESR capacitors can be used in parallel to meet the previous guidelines.

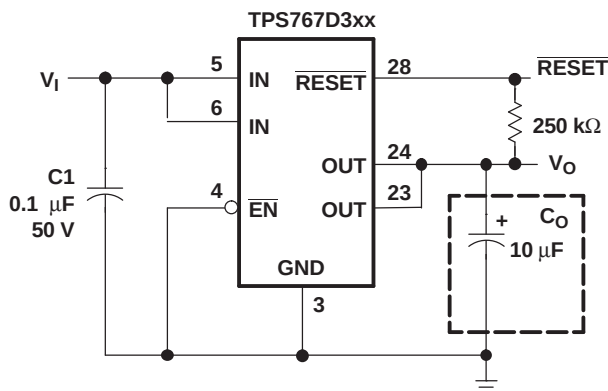


Figure 26. Typical Application Circuit (Fixed Versions) for Single Channel

Programming the TPS767D301-EP Adjustable LDO Regulator

The output voltage of the TPS767D301-EP adjustable regulator is programmed using an external resistor divider as shown in Figure 27. The output voltage is calculated using:

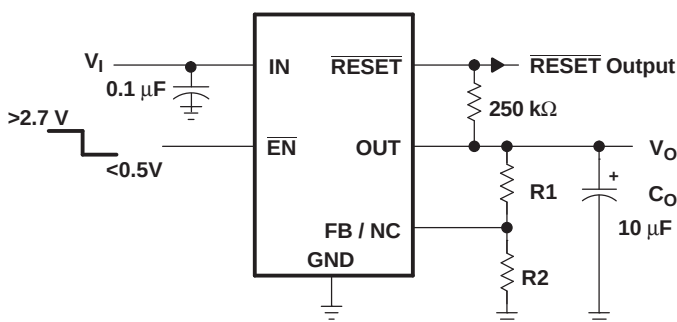
$$V_O = V_{\text{ref}} \times \left(1 + \frac{R_1}{R_2}\right)$$

where:

$$V_{\text{ref}} = 1.1834 \text{ V typ (the internal reference voltage)} \quad (1)$$

Resistors R1 and R2 should be chosen for approximately 50-μA divider current. Lower-value resistors can be used, but offer no inherent advantage and waste more power. Higher values should be avoided, as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose R2 = 30.1 kΩ to set the divider current at 50 μA and then calculate R1 using:

$$R_1 = \left(\frac{V_O}{V_{\text{ref}}} - 1\right) \times R_2 \quad (2)$$



OUTPUT VOLTAGE
PROGRAMMING GUIDE

OUTPUT VOLTAGE	R1	R2	UNIT
2.5 V	33.2	30.1	kΩ
3.3 V	53.6	30.1	kΩ
3.6 V	61.9	30.1	kΩ
4.75 V	90.8	30.1	kΩ

Figure 27. TPS767D301-EP Adjustable LDO Regulator Programming

Reset Indicator

The TPS767D301-EP features a $\overline{\text{RESET}}$ output that can be used to monitor the status of the regulator. The internal comparator monitors the output voltage. When the output drops to 95% (typical) of its regulated value, the $\overline{\text{RESET}}$ output transistor turns on, taking the signal low. The open-drain output requires a pullup resistor. If not used, it can be left floating. $\overline{\text{RESET}}$ can be used to drive power-on reset circuitry or as a low-battery indicator.

Regulator Protection

The TPS767D301-EP PMOS-pass transistor has a built-in back-gate diode that safely conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS767D301-EP also features internal current limiting and thermal protection. During normal operation, the TPS767D301-EP limits output current to approximately 1.7 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 150°C (typ), thermal-protection circuitry shuts it down. Once the device has cooled below 130°C (typ), regulator operation resumes.

Power Dissipation and Junction Temperature

Specified regulator operation is assured to a junction temperature of 125°C; the maximum junction temperature should be restricted to 125°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_D , which must be less than or equal to $P_{D(max)}$.

The maximum power dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_{Jmax} - T_A}{R_{\theta JA}}$$

where:

T_{Jmax} is the maximum allowable junction temperature

$R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package, i.e., 27.9°C/W for the 28-terminal PWP with no airflow.

T_A is the ambient temperature.

(3)

The regulator dissipation is calculated using:

$$P_D = (V_I - V_O) \times I_O \quad (4)$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation triggers the thermal protection circuit.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS767D301MPWPREP	NRND	Production	HTSSOP (PWP) 28	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-55 to 125	767D301EP
TPS767D301MPWPREP.A	NRND	Production	HTSSOP (PWP) 28	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-55 to 125	767D301EP
V62/06617-01XE	NRND	Production	HTSSOP (PWP) 28	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-55 to 125	767D301EP

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

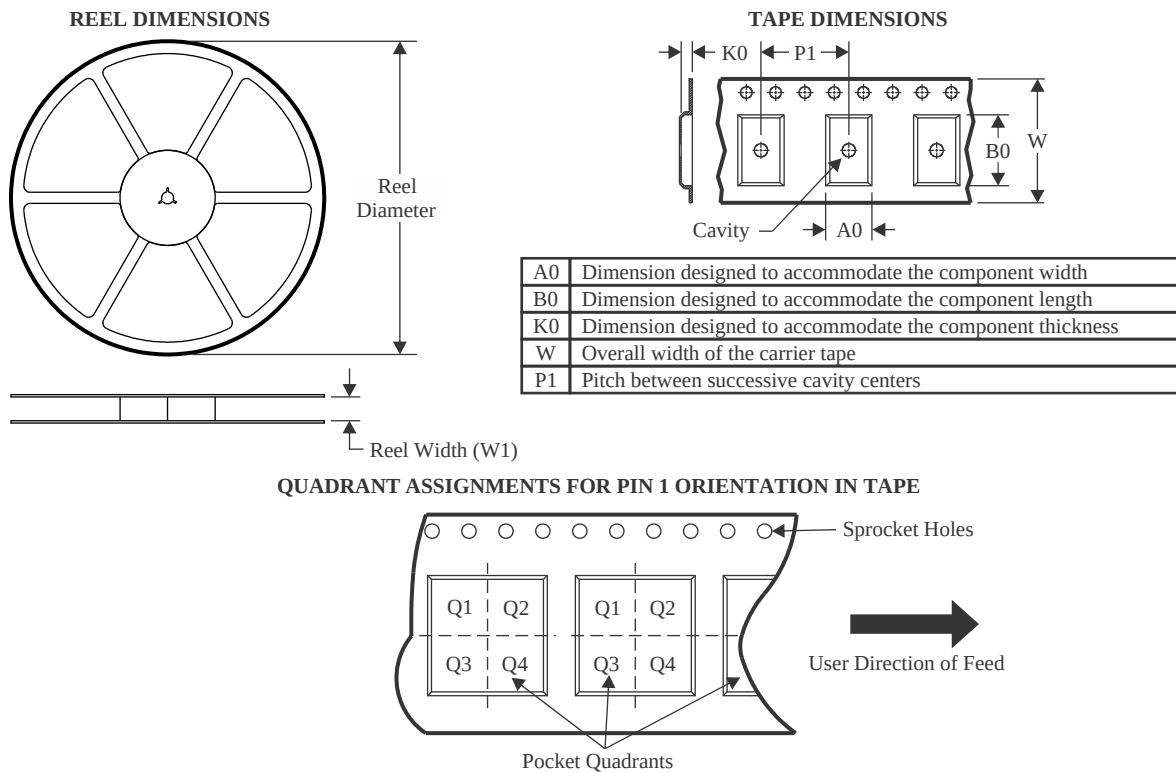
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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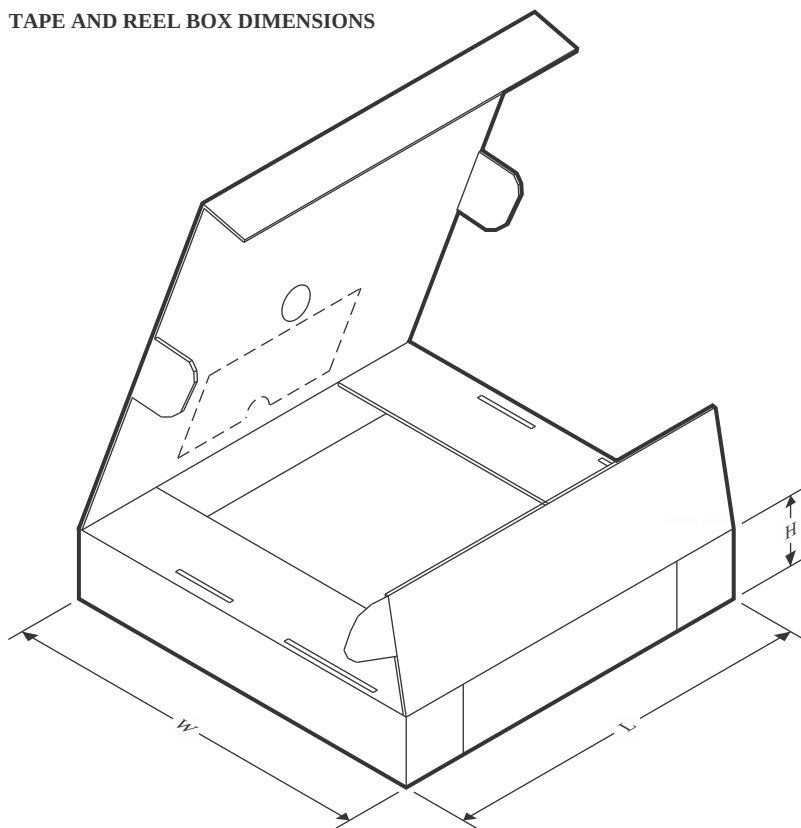
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS767D301MPWPREP	HTSSOP	PWP	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS767D301MPWPREP	HTSSOP	PWP	28	2000	350.0	350.0	43.0

GENERIC PACKAGE VIEW

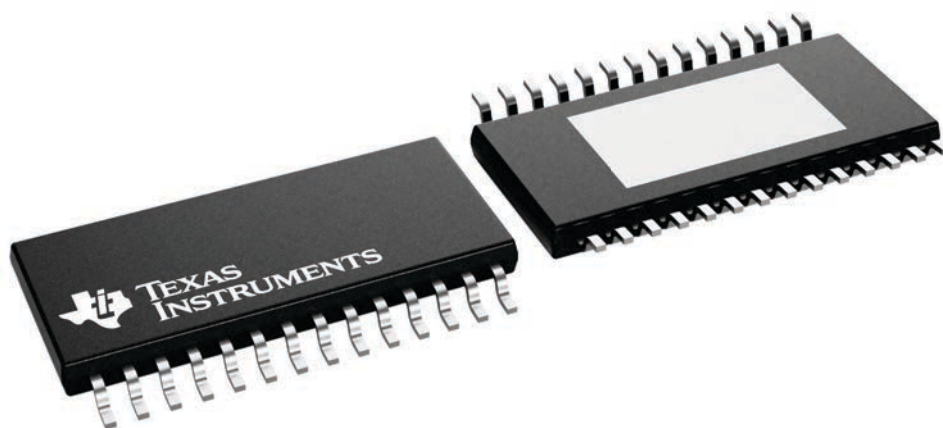
PWP 28

PowerPAD™ TSSOP - 1.2 mm max height

4.4 x 9.7, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



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